

TI *Live!* POWER SUPPLY DESIGN SEMINAR

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ISOLATED GATE-DRIVER BIAS-SUPPLY DESIGN
CONSIDERATIONS

Agenda

- Inverter and isolated gate-driver bias-supply architectures.
- Different ways of creating an isolated bias supply:
 - Control method.
 - Topology.
 - Transformer.
- LLC-based open-loop isolated bias supply:
 - Operation principles.
 - Circuit variations.
 - Voltage regulation.
 - Multiple outputs.
 - Design procedure.
- Performance demonstration.

Isolated gate drivers in different applications



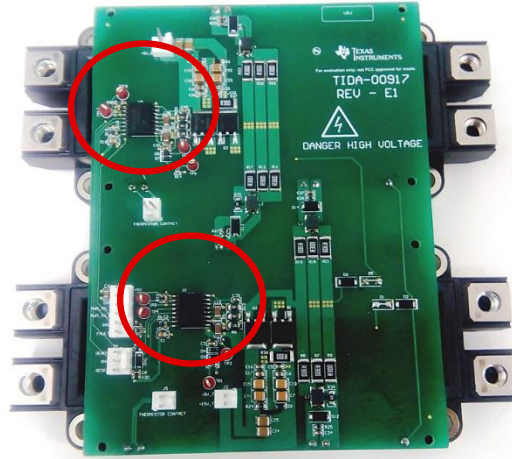
Traction inverter



UPS



Onboard charger

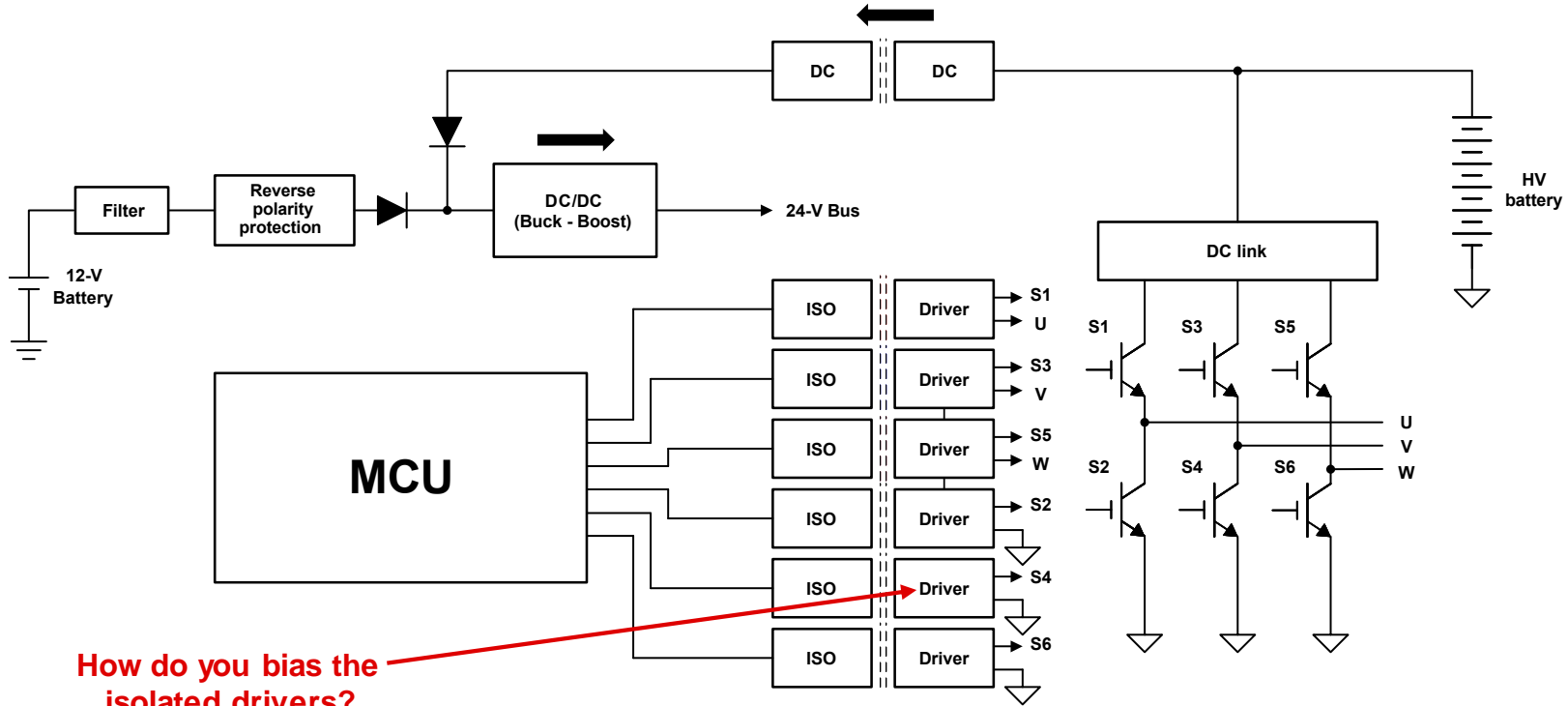


Inverter and isolated gate drivers



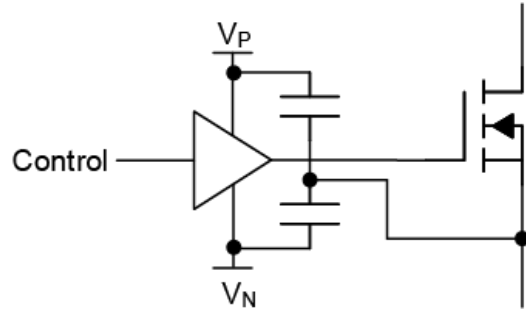
Motor drive

Example: automotive traction inverter



How do you bias the isolated drivers?

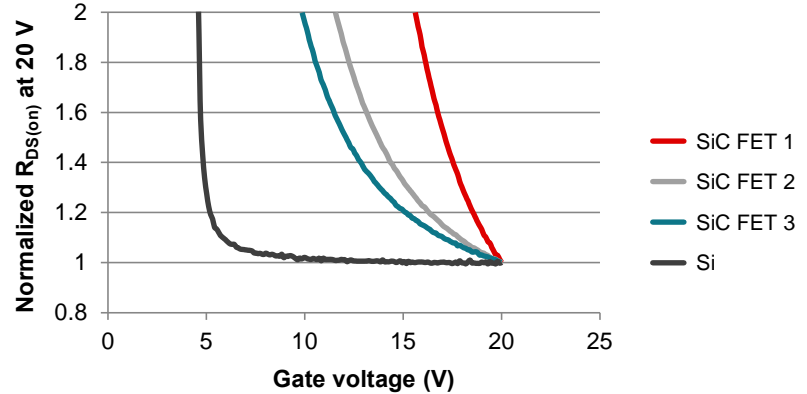
Gate-driver requirements



Gate-driver power

$$P_{DRV} = (V_P - V_N) \times Q_g \times f_{sw}$$

$$= V_{DRV} \times Q_g \times f_{sw}$$

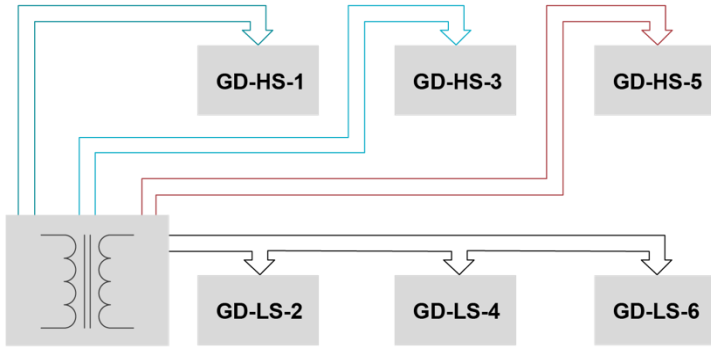


- $R_{DS(on)}$ is normalized with a 20-V gate-voltage value.
- SiC FET shows no $R_{DS(on)}$ saturation, lower $R_{DS(on)}$ with higher V_{GS} .

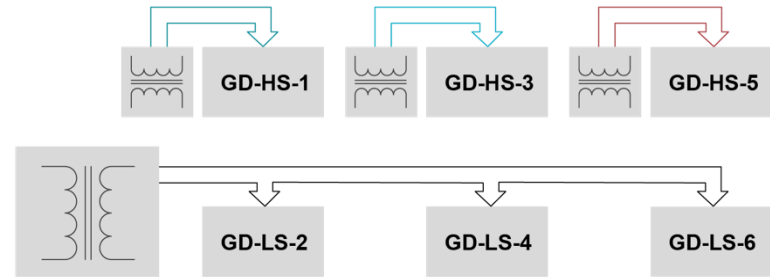
	Si MOSFET	SiC MOSFET	IGBT
Positive rail (V_P)	+12 V, +15 V	+18 V, +20 V (5%, 3%, 1%)	+15 V, +18 V
Negative rail (V_N)	0 V	-5 V, -4 V, -3 V	-8 V or 0 V

Different gate-driver architectures

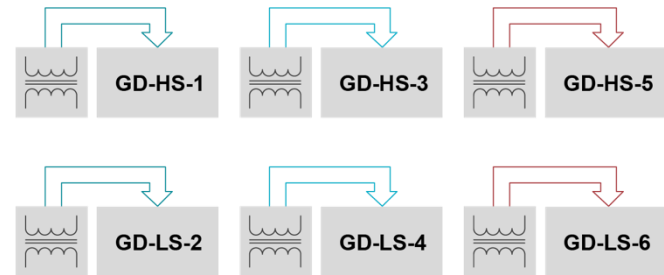
Centralized



Semidistributed

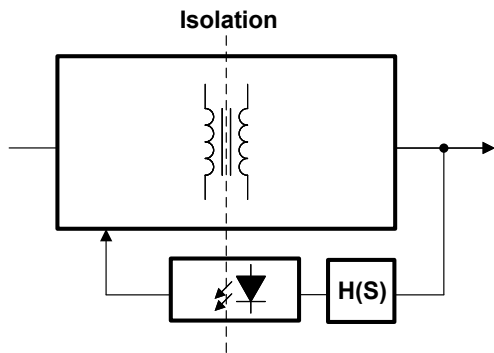


Distributed



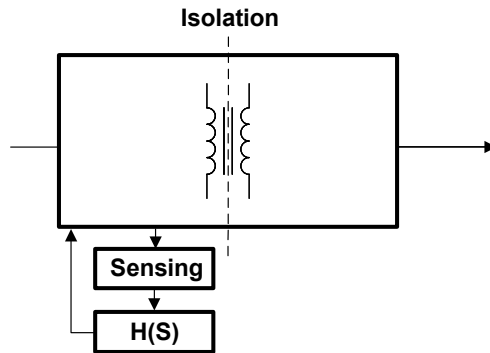
- A centralized system has the lowest cost, but is heavy and difficult to manage faults.
- A distributed system distributes the weight and fault, but is more expensive.
- A semidistributed system has the trade-off between cost and reliability.

Output voltage control



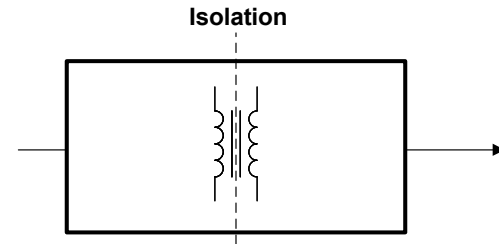
Closed loop
Secondary-side feedback

- Well-regulated output.
- Pre-regulator not necessary.
- **More components.**
- **Less reliable because of the optocoupler.**



Closed loop
Primary-side feedback

- Semiregulated output.
 - Sense auxiliary winding voltage.
- Pre-regulator not necessary.
- **Noise sensitive given the output-voltage-sampling method.**



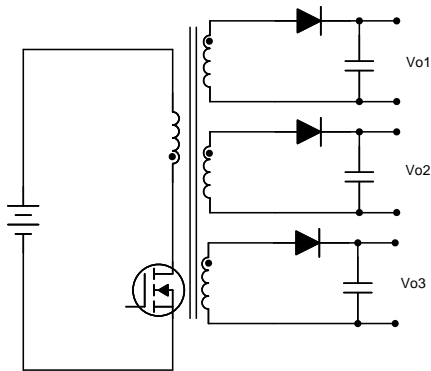
Open loop
No feedback

- No control loop, always-stable operation.
- Less noise sensitivity.
- **Unregulated output, requires a pre-regulator.**

Open-loop control provides a reliable solution.

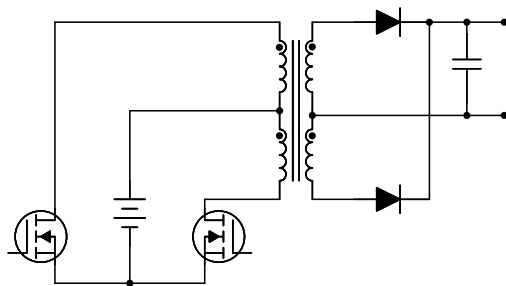
Topologies used for an isolated bias supply

Flyback



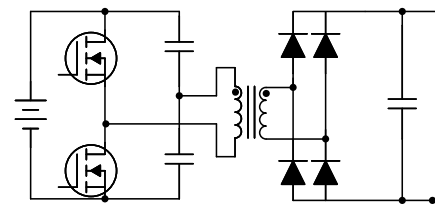
- The flyback can easily create multiple outputs:
 - Voltage proportional to the turns ratio.
 - Cross-regulation is less of an issue because of balanced loads.
 - Suitable for a centralized architecture.
- Can be controlled with opto- or primary-side feedback

Push-pull



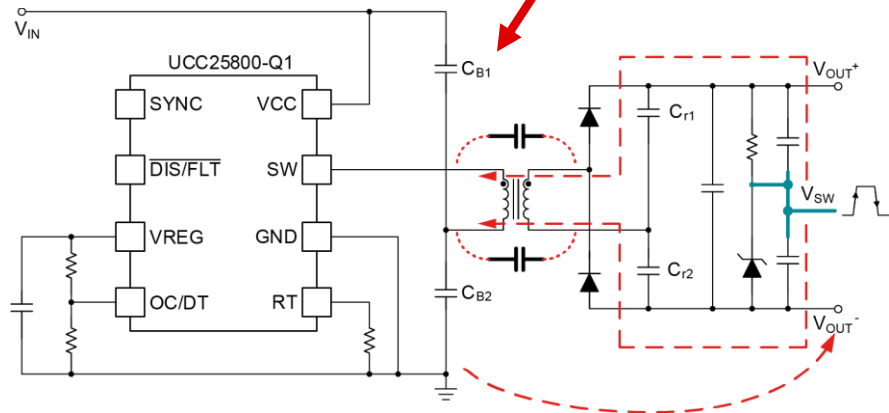
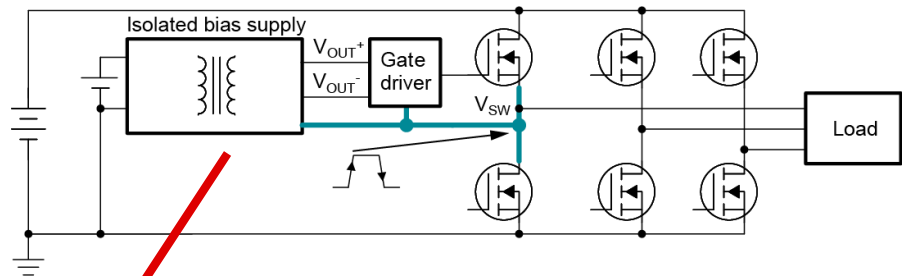
- With 50% duty-cycle open-loop operation, the output connects to the input through the transformer.
- A filter inductor is required if the duty cycle is less than 50% in order to regulate the output voltage for closed-loop operation.
- Good for distributed and semidistributed architectures.

Half or full bridge



- 50% duty cycle operation; output connects to input through the transformer.
- Can be implemented with a gate-driver IC and a simple timer.
- Good for distributed and semidistributed architectures.

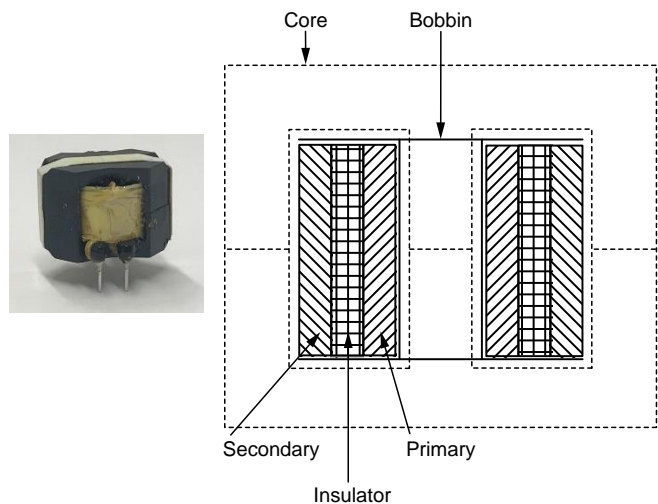
Transformer parameter impacts to system EMI



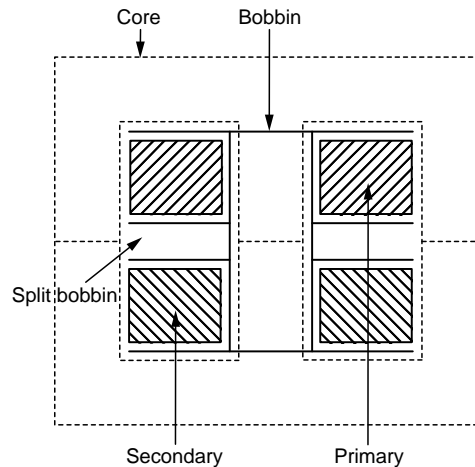
- High dv/dt couples through the transformer parasitic capacitor to the primary side.
- Higher EMI noise.
- Extra loss.
- More noise to the controller; a common-mode transient immunity (CMTI) issue.
- Noise gets worse with SiC or GaN devices with higher dv/dt .

$$i = C \frac{dv}{dt} = 1 \text{ pF} \times \frac{100 \text{ V}}{\text{ns}} = 0.1 \text{ A}$$

Transformer structure: less parasitic capacitance



$$C = \frac{\epsilon A}{d}$$



- Increasing the insulator thickness reduces the capacitance.
- Less effective given the large surface area.

- A split bobbin reduces the capacitance by reducing the surface area and increasing the distance.
- A much smaller capacitance is possible.

Increasing the distance reduces the capacitance while increasing the leakage inductance.

Transformers for an isolated bias supply

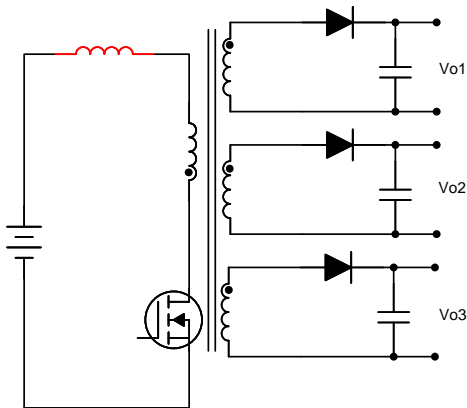
	Split-chamber transformer	Push-pull transformer	Three-winding flyback	Two-winding PSR flyback	Half bridge
C_{Pri-Sec}	<2 pF	≈10 pF	≈20 pF	≈20 pF	≈20 pF
CMTI	>150 V/ns	Worse	Worse	Much worse	Much worse
Cost comparison	Baseline	15% more expensive	30% more expensive	18% more expensive	18% more expensive
Leakage inductance	High	Very low	Low	Low	Low
Regulation	Good	Good	Better	Best	Good

6-W designs

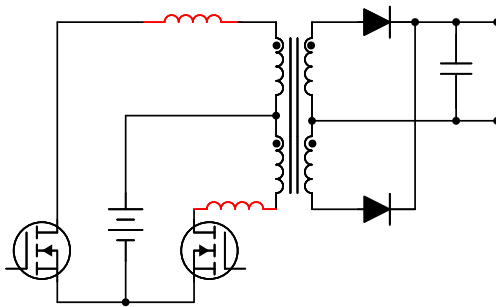
A split-chamber transformer provides an order-of-magnitude capacitance reduction.

How topologies respond to leakage inductance

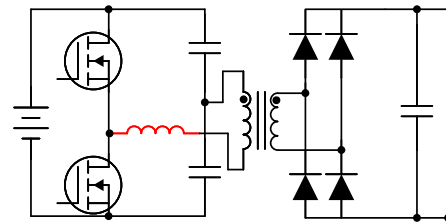
Flyback



Push-pull



Half bridge

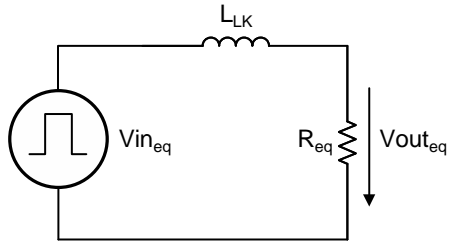
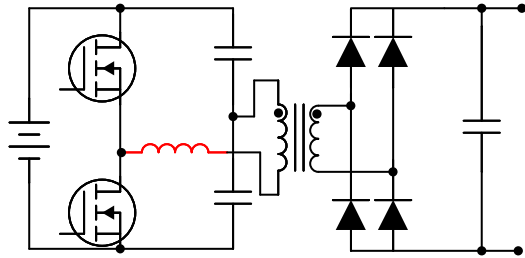


- Leakage energy can't be transferred to the secondary side.
- Leakage causes:
 - More EMI noise because of ringing.
 - More loss.
 - More device stress.
- Leakage needs minimizing.

- Leakage energy is fully recoverable.
- No extra ringing caused by leakage.
- Leakage still needs minimizing in order to obtain better voltage regulation.

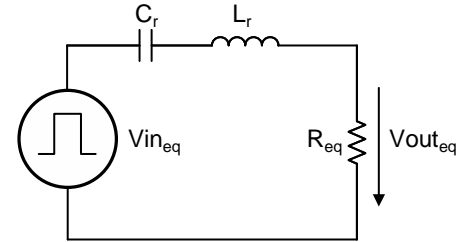
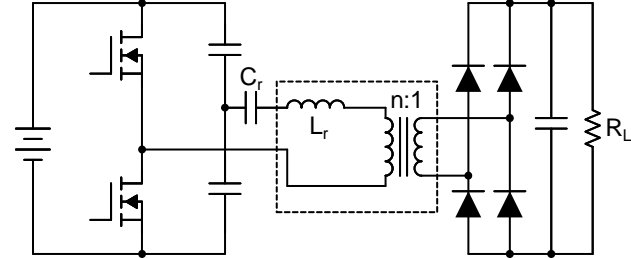
PWM converter vs. resonant converter

PWM converter



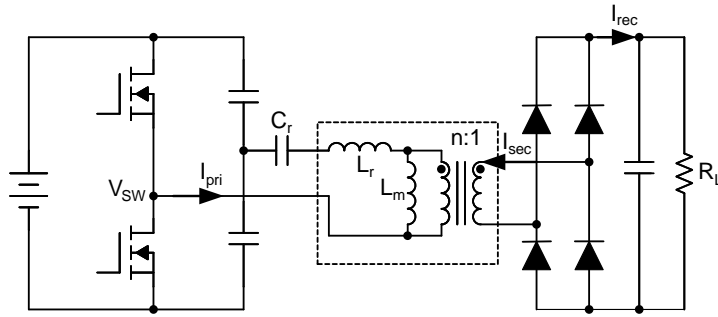
- Leakage inductance needs minimizing in order to reduce its voltage drop.

Resonant converter



- It is possible to **tune the resonant tank impedance to zero** without causing a voltage drop.

LLC converter

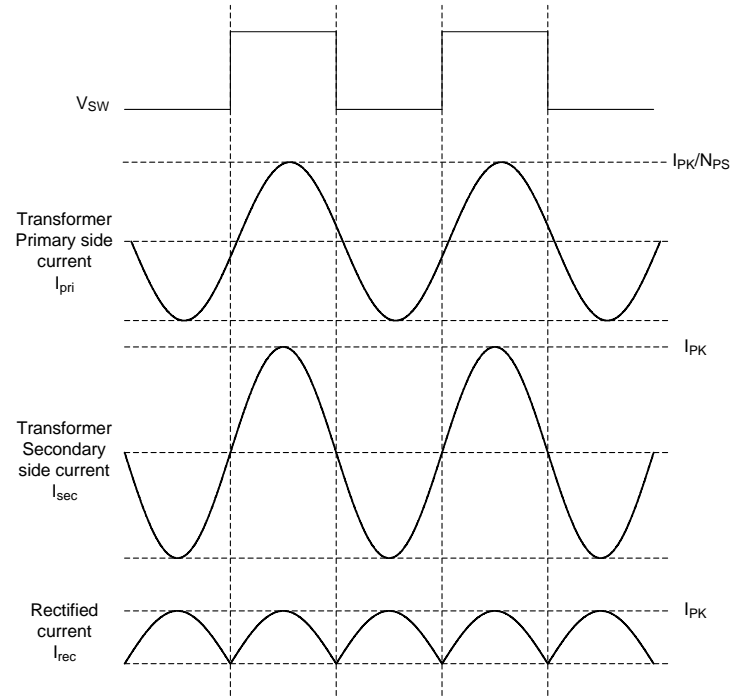
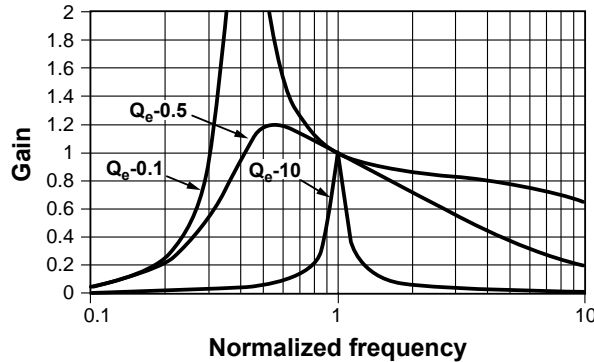


$$\text{Gain} = 2nV_o/V_{in}$$

$$f_0 = \frac{1}{2\pi\sqrt{L_r C_r}}$$

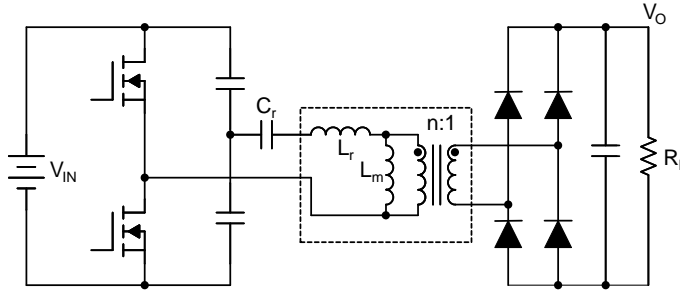
$$Q_e = \frac{\sqrt{L_r/C_r}}{R_e}$$

$$R_e = \frac{8n^2}{\pi^2} R_L$$



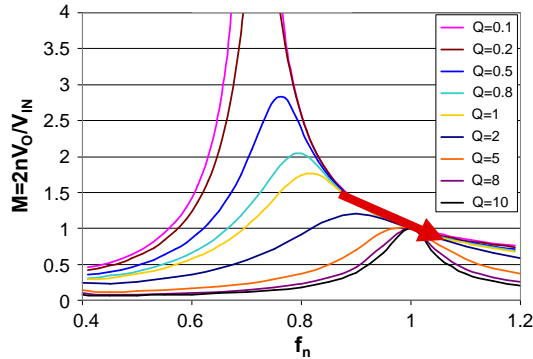
- At resonant frequency, the impedance of the resonant tank is equal to zero; the input and output are shorted through the transformer. Fixed frequency open-loop control is possible.
- You can use the leakage inductance of the transformer as the resonant inductor.

LLC gain curves with different leakage

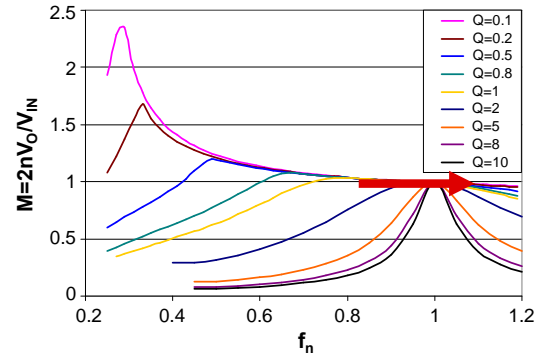


$$L_n = \frac{L_m}{L_r} = \frac{1}{\text{percentage leakage}}$$

$L_n=1$

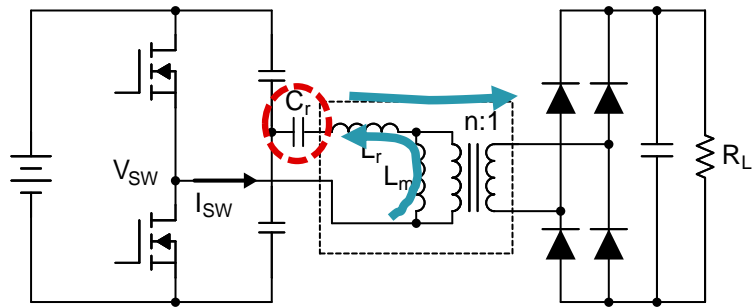


$L_n=15$

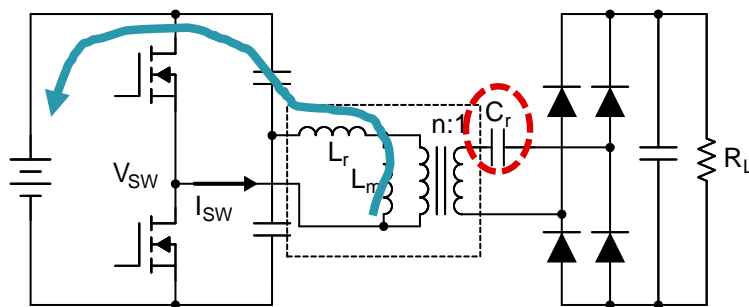
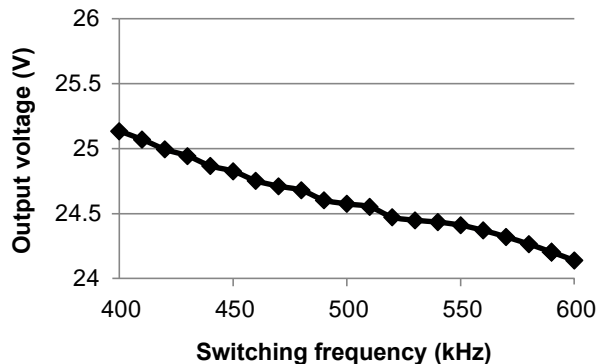


- When the magnetizing inductor is much larger than the resonant inductor, at around resonant frequency, the voltage gain curve is flat.
- The output voltage is less sensitive to the frequency error when L_n is larger.

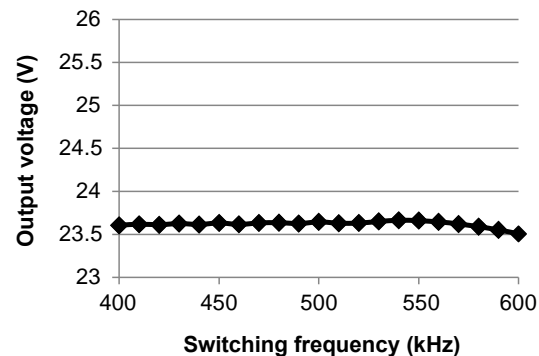
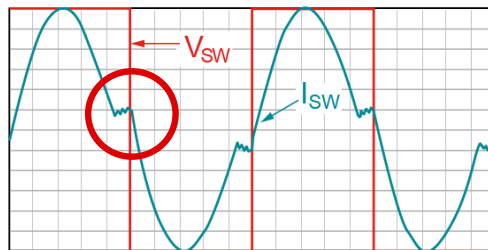
Primary- vs. secondary-side resonant



Primary-side resonant

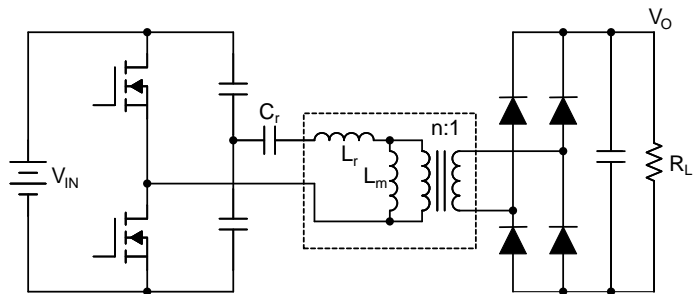


Secondary-side resonant



Secondary-side resonant is less sensitive to switching frequency errors.

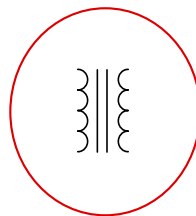
LLC converter variations



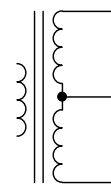
The filter capacitance needs to be much larger than the resonant capacitance.

Transformer variations

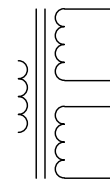
Two windings



Center tap

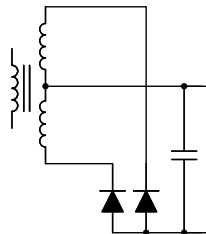


Multioutput

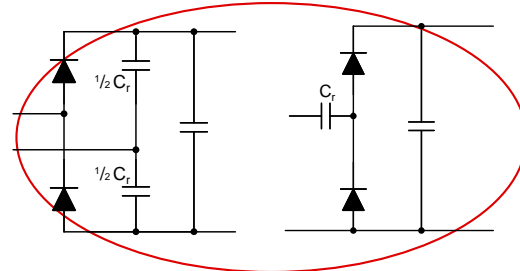


Rectification variations

Center tap

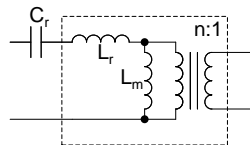


Voltage doubler

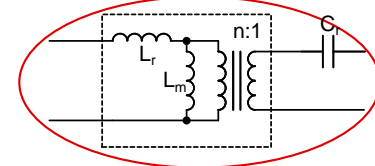


Resonant variations

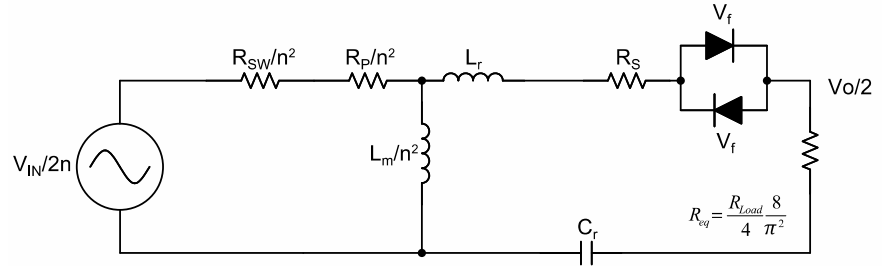
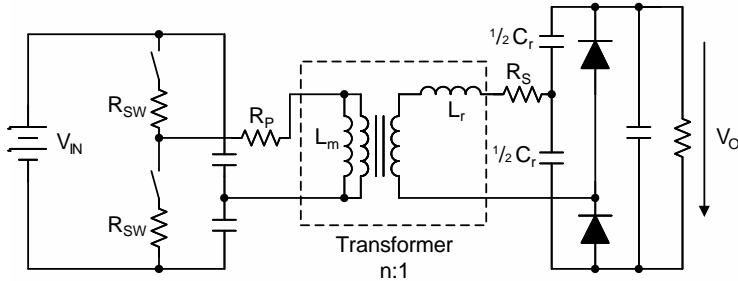
Primary-side resonant



Secondary-side resonant



Open-loop LLC voltage regulation

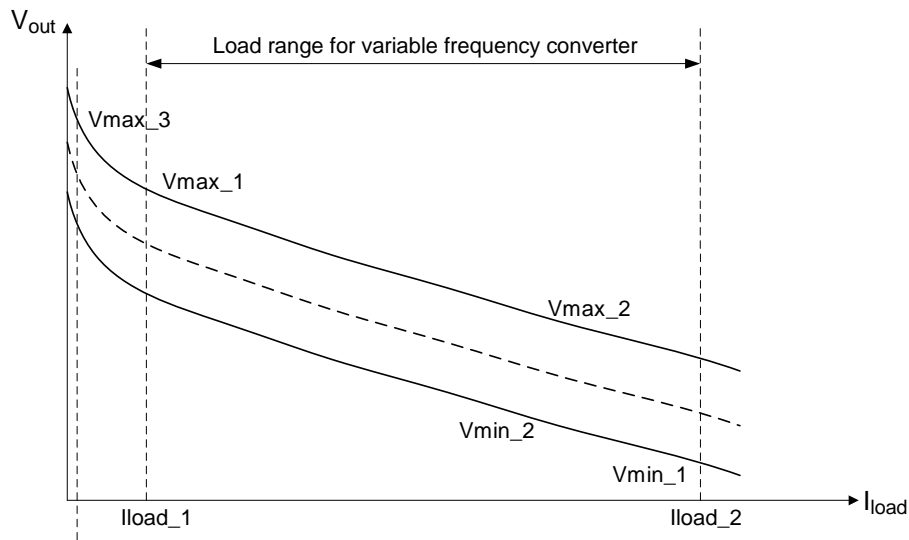


At resonant frequency

$$v_o \approx \underbrace{\frac{v_{in}}{n}}_{\text{DC voltage}} - 2v_f - \underbrace{\frac{\pi^2}{2} \left(\frac{R_{SW}}{n^2} + \frac{R_P}{n^2} + R_S \right)}_{\text{Internal resistance}} \times I_O = \frac{v_{in}}{n} - 2v_f - \frac{\pi^2}{2} \left(\frac{R_{SW}}{n^2} + R_{ac} + R_{ESR} + R_{Diode} \right) \times I_O$$

- The transformer turns ratio and resistive loss, as well as the diode drop, will determine the voltage regulation.
- Keeping the resistive loss low will result in the better load regulation.

Illustration of voltage regulation

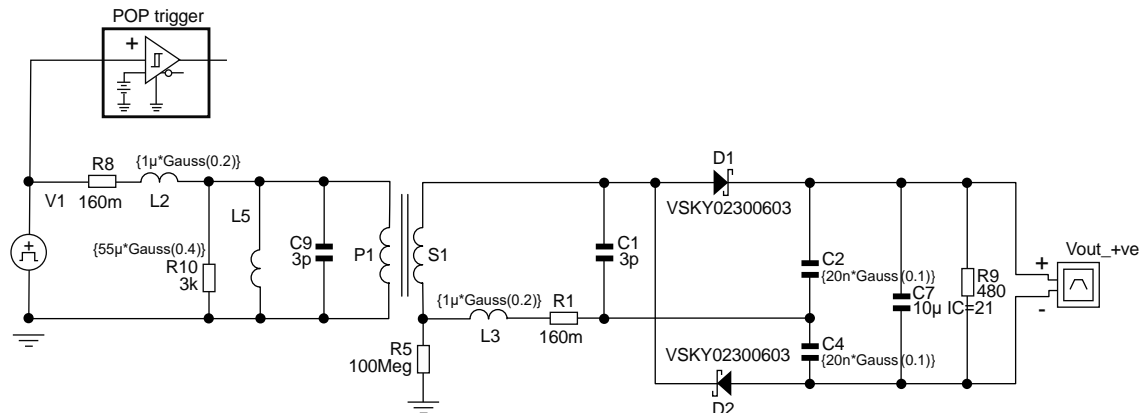


Gate-driver power

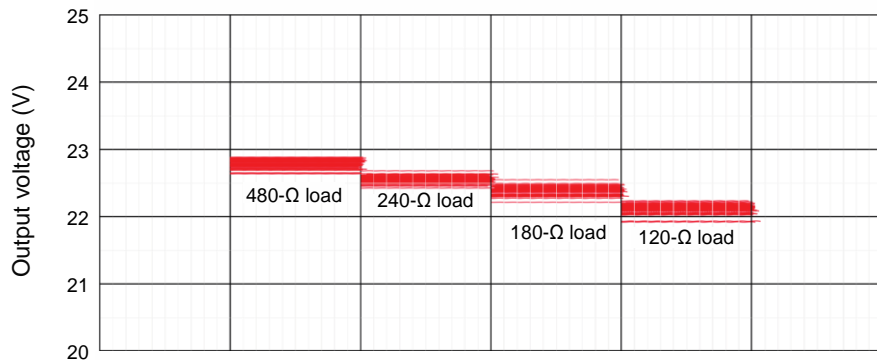
$$P_{DRV} = V_{DRV} \times Q_g \times f_{SW}$$

- The gate driver load for a fixed-switching-frequency inverter is fixed.
 - The output voltage regulation can be very tight.
- The standby-mode load voltage tends to rise.
 - Could be high enough to require an additional Zener diode clamp.
 - Mainly determined by the diode junction capacitor.
- For a variable-frequency inverter, the gate-driver load varies.
 - The output voltage varies more.

Output voltage sensitivity to tolerances



- Transformer turns ratio: 1:1.
- Leakage inductance distributed evenly on the primary and secondary sides.
 - Tolerance 20%.
- Magnetizing inductance tolerance 40%.
- Switching-frequency tolerance 6%.
- Resonant capacitance tolerance 10%.



- For each load condition, the output voltage varies $\cong 0.2$ V out of 22 V, considering all tolerances.
- Load regulation dominates voltage regulation.

Open-loop LLC design flow

Switching frequency f_{SW}

Input voltage V_{IN}

Output voltage V_{OUT}

Volt-second rating

$$VS = \frac{V_{in}}{8f_{SW}}$$

$$\frac{N_P}{N_S} = \frac{V_{in}}{V_{out} + V_{headroom}}$$

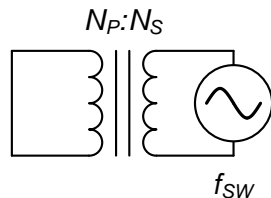
$$I_{rmsS} = \frac{\pi}{\sqrt{2}} I_{out}$$

$$I_{rmsP} = \frac{I_{rmsS}}{N_P/N_S}$$

Load current I_{OUT}

Measure leakage L_K

Primary side

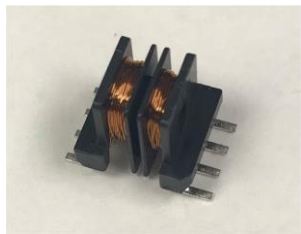


Secondary side

Calculate C_r

$$C_r = \frac{1}{4\pi^2 L_K f_r^2}$$

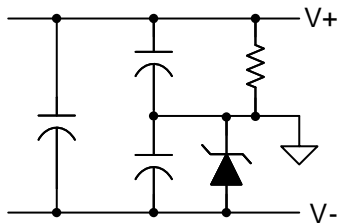
$$f_r = 1.1 f_{SW}$$



No air gap

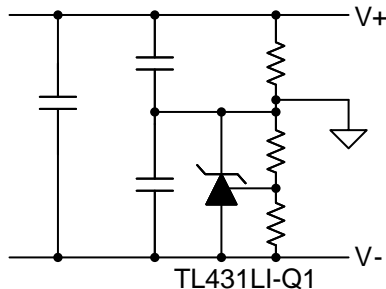
$$L_m = \frac{t_d}{8C_{SW}f_{SW}}$$

Splitting a single-output voltage into dual outputs



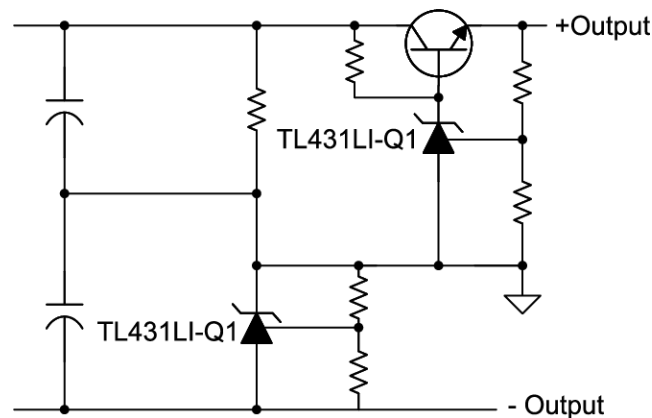
Zener split

- Lowest cost.
- Unregulated outputs.



Shunt regulator

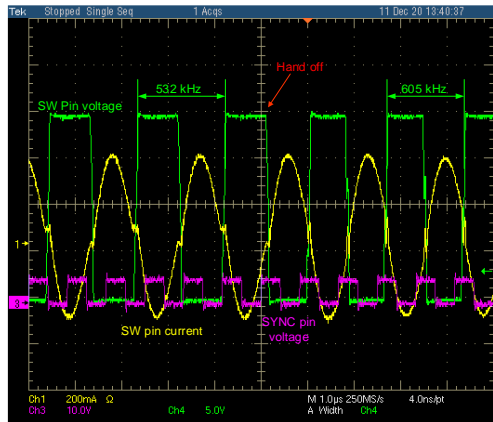
- Higher cost.
- Regulated negative output.
- Unregulated positive output.



Shunt regulator and linear regulator

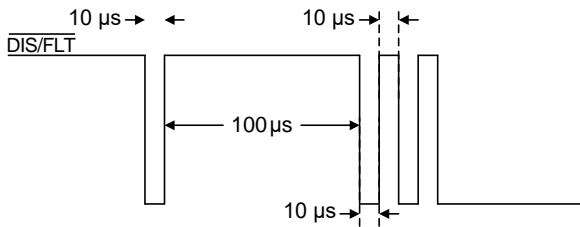
- Highest cost.
- Less efficient.
- Regulated output.

UCC25800-Q1 open-loop LLC transformer driver

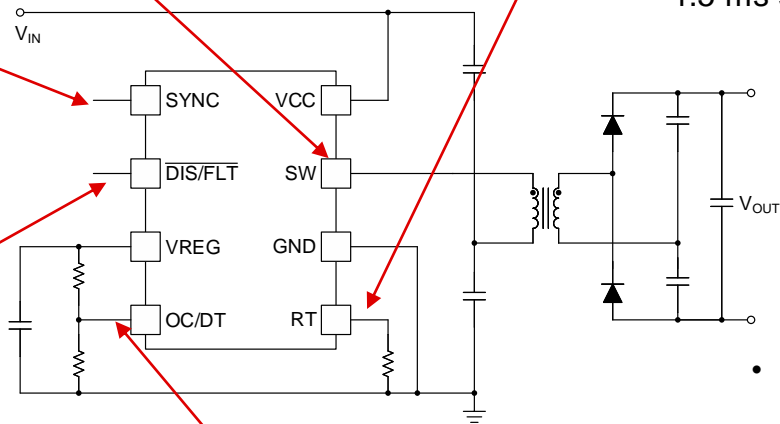


External sync

Disable and fault report



- Integrated half bridge.
- 1-A peak sinusoidal current.
- Programmable switching frequency:
 - 100 kHz to 1 MHz.
 - 1.2 MHz when left open.
 - 1.5-ms soft start.



- Programmable overcurrent protection (overload and short-circuit protections).
- Programmable maximum dead time with automatic dead-time adjustment.

- Additional protections:
 - Input OVP.
 - Thermal shutdown.
 - Pin open-short.

Open-loop LLC isolated bias-supply measurement

UCC25800 EVM with LM5156 pre-regulator

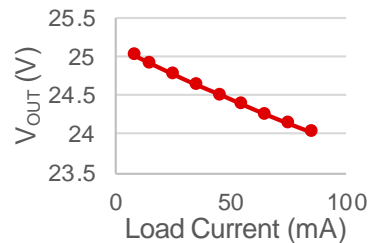


LM5156-Q1

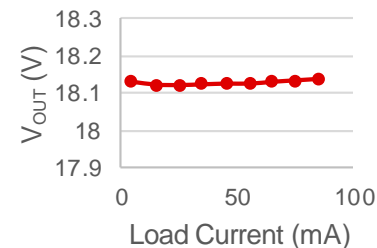
Optional components
for 1% load regulation

Parameter	Specifications
Input voltage range	6 V to 26 V
Output voltage and current	+18 V, -5 V, 0-85 mA
Switching frequency	2.2 MHz and 500 kHz
Isolation	Yes: 2,500 V _{AC} (1 s)
Topology	SEPIC + open-loop LLC transformer driver

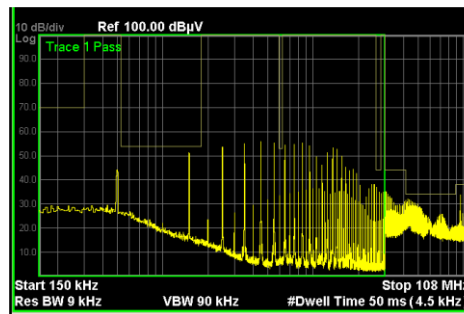
Load regulation



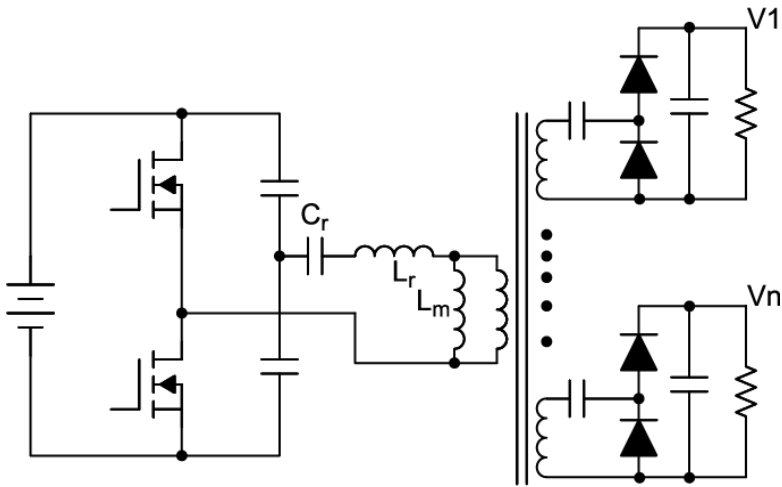
1% load regulation



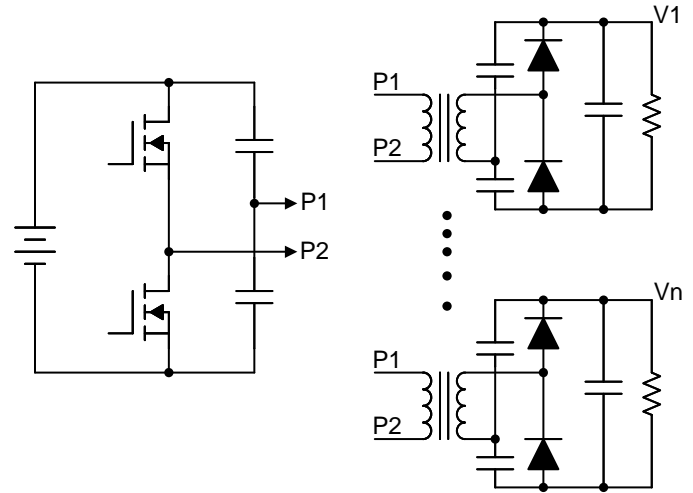
Surpasses CISPR 25 Class 5 EMI standard



Multiple outputs

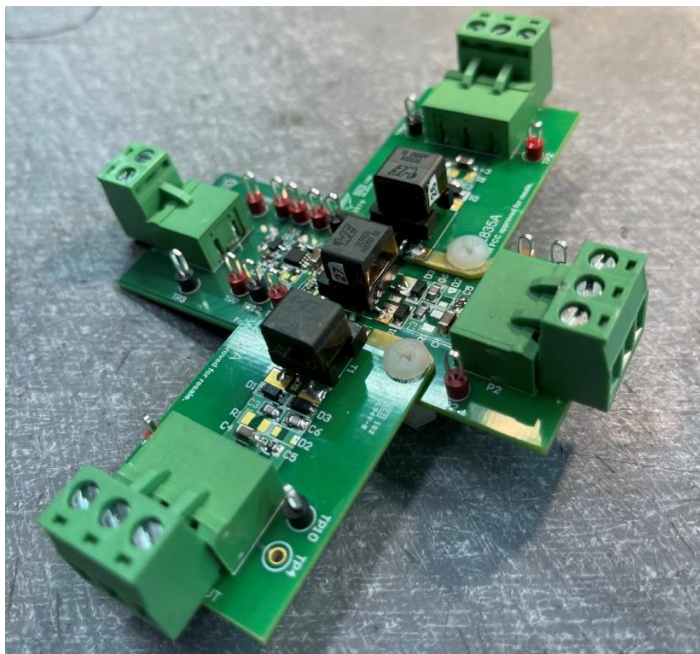


- Driving one transformer with multiple secondary-side windings.
- Uses primary-side resonant.
- Still has noise coupling among different outputs.

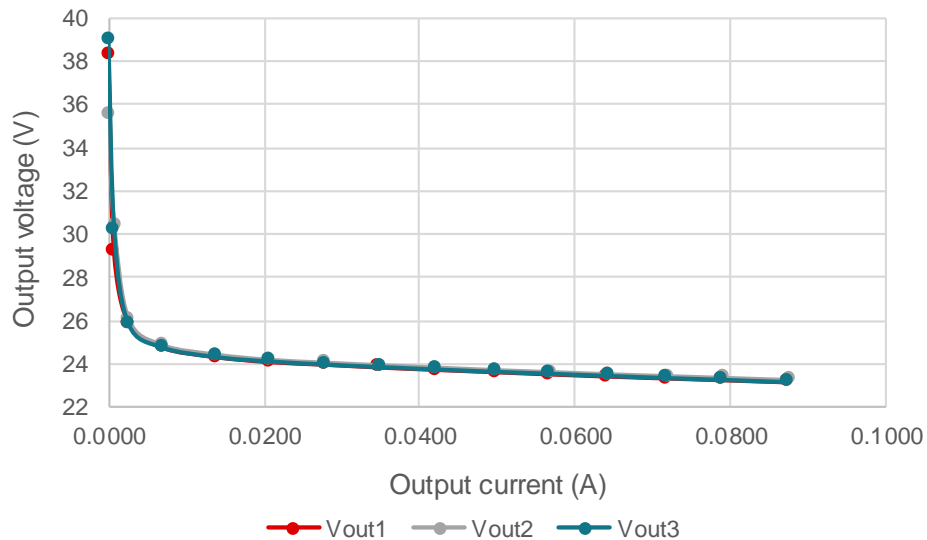


- Driving multiple two-winding transformers.
- Uses secondary-side resonant.
- Minimum noise coupling among different outputs.

Example: driving multiple transformers

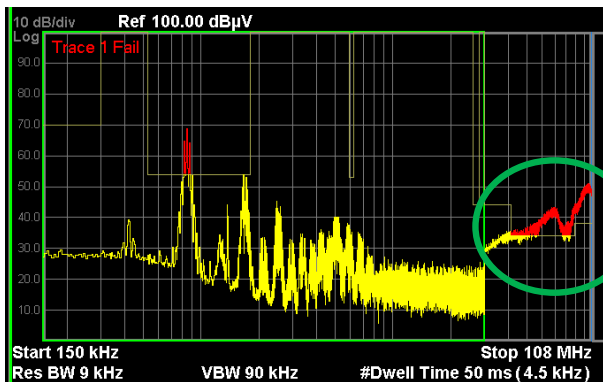


Converter voltage regulation with balanced loading, $V_{IN} = 25\text{ V}$

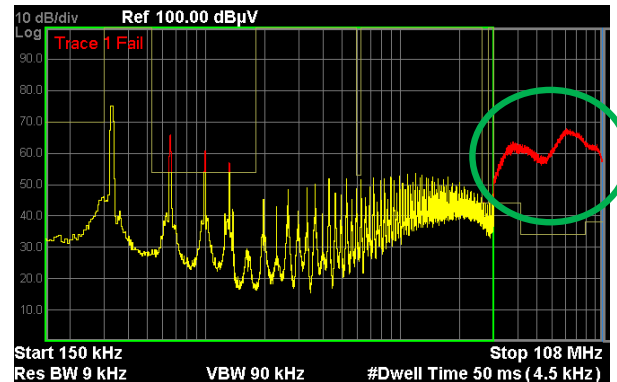


- Single primary-side power stage drives three transformers and secondary-side circuits.
- Creates three matched output voltages.

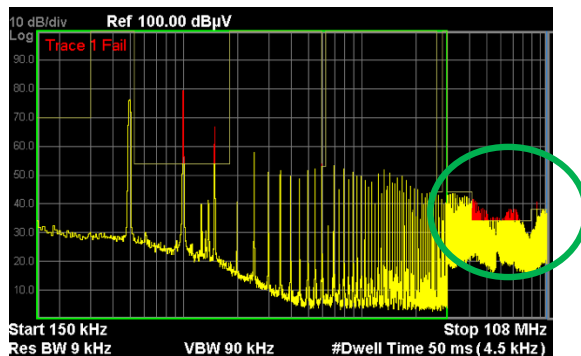
EMI noise performance comparison



5-V push-pull



24-V flyback

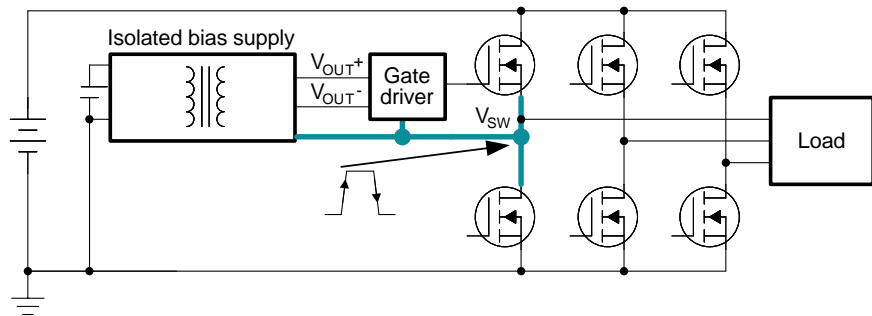


24-V LLC

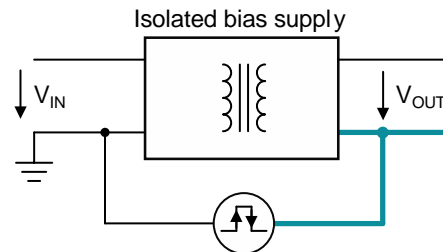
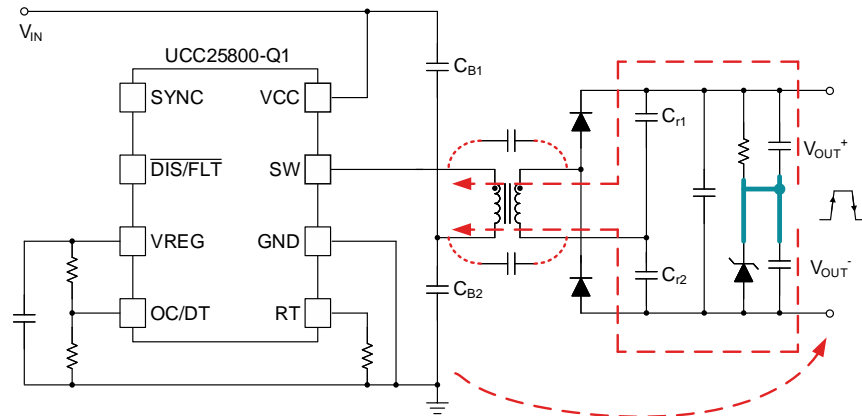
The LLC has much lower high-frequency EMI noise.

*No EMI filter added

CMTI considerations

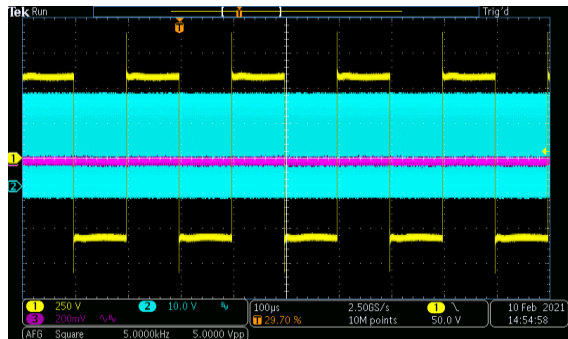


- dv/dt can reach >50 V/ns.
- Can be simulated by adding a pulse voltage between the bias-supply input and output ground.

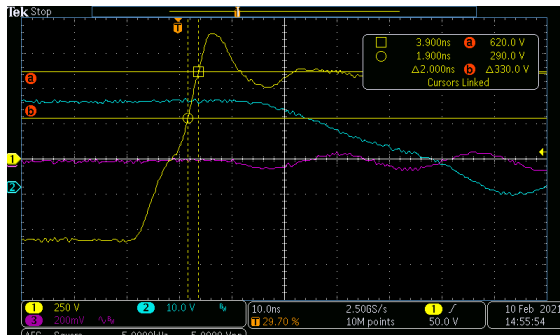


Strike voltage

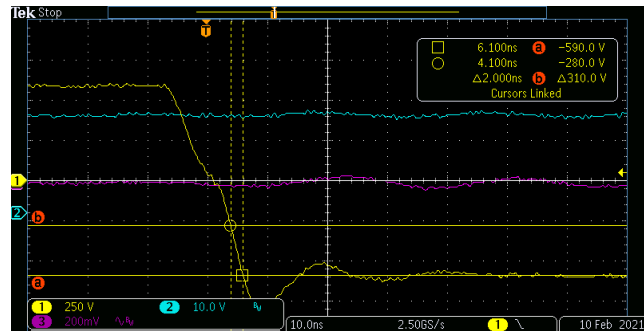
CMTI performance



165 V/ns

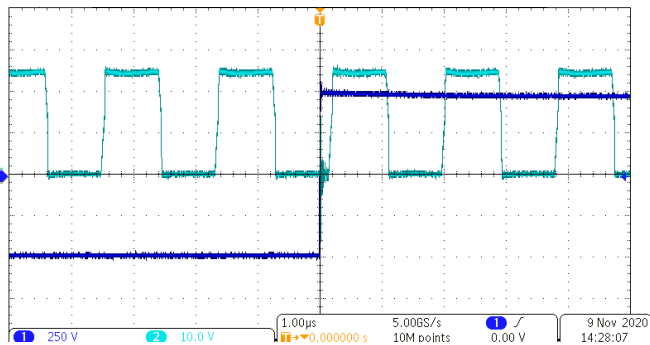


155 V/ns



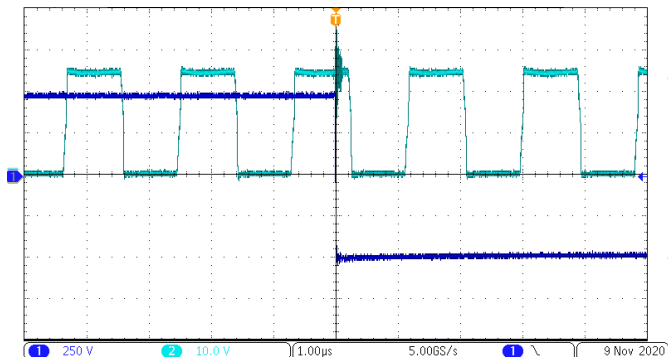
Switch node

Strike voltage



Switch node

Strike voltage



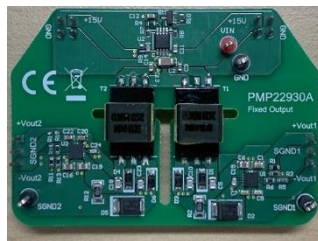
>150 V/ns CMTI does not affect operation.

Available reference designs



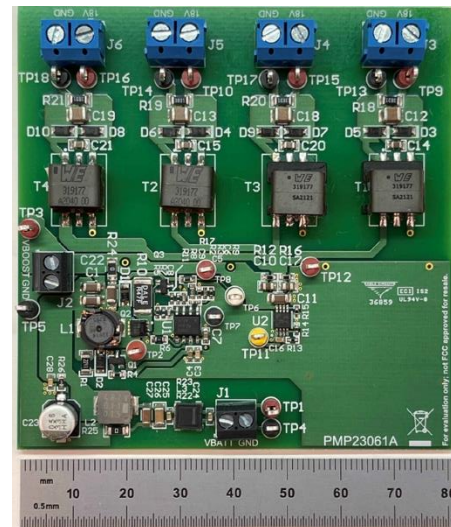
PMP22835

24-V in, 18-V and -5-V out, 6 W,
1-MHz switching frequency



PMP22930

15-V in, 15-V and -4-V out,
2.6 W, 600-kHz switching
frequency



PMP23061

6-V to 28-V in, boost
pre-regulator followed by an
LLC, three 1-W 18-V outputs,
one 3-W 18-V output, 500-kHz
switching frequency

Summary

- An isolated bias supply is necessary for biasing isolated gate drivers in inverters.
 - Open-loop control provides a reliable solution and is less noise sensitive.
- The LLC topology is able to use the transformer with large leakage inductance and minimize the transformer's primary- to secondary-side parasitic capacitance.
 - Less EMI noise.
- The open-loop LLC converter provides a simple, robust solution:
 - Less EMI.
 - High CMTI.
 - Good voltage regulation.
 - Multiple output capability.



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